Jonathan Finley

List of Publications by Year
in descending order

278 papers	10,765 citations	28274 55 h-index	40979 93 g-index
282 all docs	282 docs citations	282 times ranked	8524 citing authors

#	Article	IF	Citations
1	Tuning the Optical Properties of a MoSe₂ Monolayer Using Nanoscale Plasmonic Antennas. Nano Letters, 2022, 22, 561-569.	9.1	11
2	Trions in <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:msub><mml:mi>MoS</mml:mi><mml:mn>2</mml:mn></mml:msub></mn are quantum superpositions of intra- and intervalley spin states. Physical Review B, 2022, 105, .	3.2	11
3	Electronically Tunable Transparent Conductive Thin Films for Scalable Integration of 2D Materials with Passive 2Dâ€“3D Interfaces. Advanced Functional Materials, 2022, 32, .	14.9	3
4	Electrical control of orbital and vibrational interlayer coupling in bi- and trilayer <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:mn>2</mml:mn><mml:mi mathvariant="normal">H</mml:mi><mml:mtext>âˆ’</mml:mtext><mml:msub><mml:mi>MoS</mml:mi><mml:mn>2</mml:mn></mml:m Physical Review Materials, 2022, 6, .	2.4	4
5	Stimulated Generation of Indistinguishable Single Photons from a Quantum Ladder System. Physical Review Letters, 2022, 128, 093603.	7.8	20
6	Automated, deep reactive ion etching free fiber coupling to nanophotonic devices. , 2022, , .		2
7	Electronically Tunable Transparent Conductive Thin Films for Scalable Integration of 2D Materials with Passive 2Dâ€“3D Interfaces (Adv. Funct. Mater. 21/2022). Advanced Functional Materials, 2022, 32, .	14.9	0
8	Nonlocal Exciton-Photon Interactions in Hybrid High- <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:mi>Q</mml:mi></mml:mrow></mml:math> Beam Nanocavities with Encapsulated <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mi>MoS</mml:mi></mml:mrow><mml:mrow><mml:mn>2</mml:mn></ Monolayers. Physical Review Letters, 2022, 128, .	7.8	6
9	Unveiling the Zero-Phonon Line of the Boron Vacancy Center by Cavity-Enhanced Emission. Nano Letters, 2022, 22, 5137-5142.	9.1	18
10	Gate-Switchable Arrays of Quantum Light Emitters in Contacted Monolayer MoS₂ van der Waals Heterodevices. Nano Letters, 2021, 21, 1040-1046.	9.1	36
11	High-resolution spectroscopy of a quantum dot driven bichromatically by two strong coherent fields. Physical Review Research, 2021, 3, .	3.6	8
12	3D Deep Learning Enables Accurate Layer Mapping of 2D Materials. ACS Nano, 2021, 15, 3139-3151.	14.6	25
13	Growth dynamics and compositional structure in periodic InAsSb nanowire arrays on Si (111) grown by selective area molecular beam epitaxy. Nanotechnology, 2021, 32, 135604.	2.6	10
14	Charged Exciton Kinetics in Monolayer MoSe₂ near Ferroelectric Domain Walls in Periodically Poled LiNbO₃. Nano Letters, 2021, 21, 959-966.	9.1	7
15	Optomechanical wave mixing by a single quantum dot. Optica, 2021, 8, 291.	9.3	24
16	Controlling exciton many-body states by the electric-field effect in monolayer <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:msub><mml:mrow><mml:mi>MoS</mml:mi></mml:mrow><mml:mn>2</ Physical Review Research, 2021, 3, .	3.6	23
17	Bright Electrically Controllable Quantumâ€Dotâ€Molecule Devices Fabricated by In Situ Electronâ€Beam Lithography. Advanced Quantum Technologies, 2021, 4, 2100002.	3.9	12
18	Low-threshold strain-compensated InGaAs/(In,Al)GaAs multi-quantum well nanowire lasers emitting near 1.3 Î¼m at room temperature. Applied Physics Letters, 2021, 118, .	3.3	18

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19	Manganese doping for enhanced magnetic brightening and circular polarization control of dark excitons in paramagnetic layered hybrid metal-halide perovskites. Nature Communications, 2021, 12, 3489.	12.8	38
20	Efficient Optomechanical Mode-Shape Mapping of Micromechanical Devices. Micromachines, 2021, 12, 880.	2.9	2
21	Resonance-fluorescence spectral dynamics of an acoustically modulated quantum dot. Physical Review Research, 2021, 3, .	3.6	12
22	Engineering the Luminescence and Generation of Individual Defect Emitters in Atomically Thin MoS₂. ACS Photonics, 2021, 8, 669-677.	6.6	48
23	Raman spectrum of Janus transition metal dichalcogenide monolayers WSSe and MoSSe. Physical Review B, 2021, 103, .	3.2	63
24	Epitaxial type-I and type-II InAs-AlAsSb coreâ€“shell nanowires on silicon. Applied Physics Letters, 2021, 119, .	3.3	5
25	Purcell enhanced coupling of nanowire quantum emitters to silicon photonic waveguides. Optics Express, 2021, 29, 43068.	3.4	6
26	Quantumâ€Confinementâ€Enhanced Thermoelectric Properties in Modulationâ€Doped GaAsâ€“AlGaAs Coreâ€“Shell Nanowires. Advanced Materials, 2020, 32, e1905458.	21.0	19
27	Origin of Antibunching in Resonance Fluorescence. Physical Review Letters, 2020, 125, 170402.	7.8	22
28	Ultrathin catalyst-free InAs nanowires on silicon with distinct 1D sub-band transport properties. Nanoscale, 2020, 12, 21857-21868.	5.6	17
29	Crux of Using the Cascaded Emission of a Three-Level Quantum Ladder System to Generate Indistinguishable Photons. Physical Review Letters, 2020, 125, 233605.	7.8	34
30	Time-domain photocurrent spectroscopy based on a common-path birefringent interferometer. Review of Scientific Instruments, 2020, 91, 123101.	1.3	4
31	Atomistic defects as single-photon emitters in atomically thin MoS2. Applied Physics Letters, 2020, 117, .	3.3	51
32	Discrete interactions between a few interlayer excitons trapped at a MoSe2â€“WSe2 heterointerface. Npj 2D Materials and Applications, 2020, 4, .	7.9	54
33	Demonstration of <i>n</i>-type behavior in catalyst-free Si-doped GaAs nanowires grown by molecular beam epitaxy. Applied Physics Letters, 2020, 116, .	3.3	14
34	Direct-bandgap emission from hexagonal Ge and SiGe alloys. Nature, 2020, 580, 205-209.	27.8	231
35	Line-Scan Hyperspectral Imaging Microscopy with Linear Unmixing for Automated Two-Dimensional Crystals Identification. ACS Photonics, 2020, 7, 1216-1225.	6.6	13
36	Signatures of a degenerate many-body state of interlayer excitons in a van der Waals heterostack. Physical Review Research, 2020, 2, .	3.6	42

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37	Ultracompact Photodetection in Atomically Thin MoSe₂. ACS Photonics, 2019, 6, 1902-1909.	6.6	15
38	Optical absorption of composition-tunable InGaAs nanowire arrays. Nanotechnology, 2019, 30, 495703.	2.6	11
39	Site-selectively generated photon emitters in monolayer MoS2 via local helium ion irradiation. Nature Communications, 2019, 10, 2755.	12.8	132
40	Optimized waveguide coupling of an integrated III-V nanowire laser on silicon. Journal of Applied Physics, 2019, 125, .	2.5	10
41	Breakdown of Corner States and Carrier Localization by Monolayer Fluctuations in Radial Nanowire Quantum Wells. Nano Letters, 2019, 19, 3336-3343.	9.1	14
42	Resonance Fluorescence of GaAs Quantum Dots with Near-Unity Photon Indistinguishability. Nano Letters, 2019, 19, 2404-2410.	9.1	63
43	Impact of substrate induced band tail states on the electronic and optical properties of MoS2. Applied Physics Letters, 2019, 115, .	3.3	24
44	Nanoscale mapping of carrier recombination in GaAs/AlGaAs core-multishell nanowires by cathodoluminescence imaging in a scanning transmission electron microscope. Applied Physics Letters, 2019, 115, 243102.	3.3	4
45	Toward Plasmonic Tunnel Gaps for Nanoscale Photoemission Currents by On-Chip Laser Ablation. Nano Letters, 2019, 19, 1172-1178.	9.1	35
46	Tuning Lasing Emission towards Long Wavelengths in GaAs-(In,Al)GaAs Core-Multishell Nanowires. , 2019, , .		0
47	Waveguide Coupling of an Integrated Nanowire Laser on Silicon with Enhanced End-Facet Reflectivity. , 2019, , .		0
48	Carrier concentration dependent photoluminescence properties of Si-doped InAs nanowires. Applied Physics Letters, 2018, 112, .	3.3	14
49	Correlated Chemical and Electrically Active Dopant Analysis in Catalyst-Free Si-Doped InAs Nanowires. ACS Nano, 2018, 12, 1603-1610.	14.6	13
50	Pulsed Rabi oscillations in quantum two-level systems: beyond the area theorem. Quantum Science and Technology, 2018, 3, 014006.	5.8	29
51	Slow light enhanced gas sensing in photonic crystals. Optical Materials, 2018, 76, 106-110.	3.6	31
52	Carrier trapping and activation at short-period wurtzite/zinc-blende stacking sequences in polytypic InAs nanowires. Physical Review B, 2018, 97, .	3.2	10
53	The Dielectric Impact of Layer Distances on Exciton and Trion Binding Energies in van der Waals Heterostructures. Nano Letters, 2018, 18, 2725-2732.	9.1	113
54	Robust valley polarization of helium ion modified atomically thin MoS ₂. 2D Materials, 2018, 5, 011007.	4.4	55

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55	Tuning Lasing Emission toward Long Wavelengths in GaAs-(In,Al)GaAs Coreâ€“Multishell Nanowires. Nano Letters, 2018, 18, 6292-6300.	9.1	43
56	Quantum dot single-photon sources with ultra-low multi-photon probability. Npj Quantum Information, 2018, 4, .	6.7	114
57	He-Ion Microscopy as a High-Resolution Probe for Complex Quantum Heterostructures in Coreâ€“Shell Nanowires. Nano Letters, 2018, 18, 3911-3919.	9.1	13
58	GaN Nanowire Arrays for Efficient Optical Read-Out and Optoelectronic Control of NV Centers in Diamond. Nano Letters, 2018, 18, 3651-3660.	9.1	12
59	Bandgap Engineering of Graphene Nanoribbons by Control over Structural Distortion. Journal of the American Chemical Society, 2018, 140, 7803-7809.	13.7	68
60	Quantum dot single photon sources with ultra-low multi-photon error rate. , 2018, , .		1
61	Coupling Single Photons from Discrete Quantum Emitters in WSe₂ to Lithographically Defined Plasmonic Slot Waveguides. Nano Letters, 2018, 18, 6812-6819.	9.1	53
62	Long-lived Quantum Emitters in hBN-WSe2 Van-Der-Waals Heterostructures. , 2018, , .		0
63	Two-photon bundles from a single two-level system. , 2018, , .		0
64	Silicon Waveguide Coupled III-V Nanowire Lasers with Epitaxial Gain Control. , 2018, , .		0
65	Enhanced optical activity of atomically thin MoSe 2 proximal to nanoscale plasmonic slot-waveguides. 2D Materials, 2017, 4, 021011.	4.4	13
66	Signatures of two-photon pulses from a quantum two-level system. Nature Physics, 2017, 13, 649-654.	16.7	53
67	CW and ultrafast properties of GaAs-AlGaAs core-shell nanowire lasers on silicon (Conference) Tj ETQq1 1 0.784314 rgBT /Overlock 10 1		0
68	Enhanced THz emission efficiency of composition-tunable InGaAs nanowire arrays. Applied Physics Letters, 2017, 110, .	3.3	8
69	GaAsâ€“AlGaAs coreâ€“shell nanowire lasers on silicon: invited review. Semiconductor Science and Technology, 2017, 32, 053001.	2.0	48
70	Electric-Field Switchable Second-Harmonic Generation in Bilayer MoS₂ by Inversion Symmetry Breaking. Nano Letters, 2017, 17, 392-398.	9.1	71
71	Direct exciton emission from atomically thin transition metal dichalcogenide heterostructures near the lifetime limit. Scientific Reports, 2017, 7, 12383.	3.3	122
72	Nanometer-scale Resolved Cathodoluminescence Imaging: New Insights into GaAs/AlGaAs Core-shell Nanowire Lasers. Microscopy and Microanalysis, 2017, 23, 1470-1471.	0.4	0

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73	Direct Coupling of Coherent Emission from Site-Selectively Grown IIIâ€“V Nanowire Lasers into Proximal Silicon Waveguides. ACS Photonics, 2017, 4, 2537-2543.	6.6	34
74	Quantum Transport and Sub-Band Structure of Modulation-Doped GaAs/AlAs Coreâ€“Superlattice Nanowires. Nano Letters, 2017, 17, 4886-4893.	9.1	18
75	A few-emitter solid-state multi-exciton laser. Scientific Reports, 2017, 7, 7420.	3.3	10
76	Long-term mutual phase locking of picosecond pulse pairs generated by a semiconductor nanowire laser. Nature Communications, 2017, 8, 15521.	12.8	14
77	Optically-probing spin qubit coherence without coherent control (Conference Presentation). , 2017, , .		0
78	Metamorphic plasmonic nanoantennas for self-enhanced nonlinear light generation. Optica, 2016, 3, 1453.	9.3	8
79	Widely tunable alloy composition and crystal structure in catalyst-free InGaAs nanowire arrays grown by selective area molecular beam epitaxy. Applied Physics Letters, 2016, 108, .	3.3	27
80	Suppression of alloy fluctuations in GaAs-AlGaAs core-shell nanowires. Applied Physics Letters, 2016, 109, .	3.3	17
81	Continuous wave lasing from individual GaAs-AlGaAs core-shell nanowires. Applied Physics Letters, 2016, 108, .	3.3	24
82	Surface acoustic wave regulated single photon emission from a coupled quantum dotâ€“nanocavity system. Applied Physics Letters, 2016, 109, .	3.3	33
83	Coaxial GaAs-AlGaAs core-multishell nanowire lasers with epitaxial gain control. Applied Physics Letters, 2016, 108, .	3.3	59
84	The Native Material Limit of Electron and Hole Mobilities in Semiconductor Nanowires. ACS Nano, 2016, 10, 4942-4953.	14.6	26
85	Emission redistribution from a quantum dot-bowtie nanoantenna. Journal of Nanophotonics, 2016, 10, 033509.	1.0	11
86	Integrated superconducting detectors on semiconductors for quantum optics applications. Applied Physics B: Lasers and Optics, 2016, 122, 1.	2.2	14
87	Advances in semiconductor nanowire lasers. , 2016, , .		0
88	Direct Measurements of Fermi Level Pinning at the Surface of Intrinsically n-Type InGaAs Nanowires. Nano Letters, 2016, 16, 5135-5142.	9.1	60
89	Microscopic nature of crystal phase quantum dots in ultrathin GaAs nanowires by nanoscale luminescence characterization. New Journal of Physics, 2016, 18, 063009.	2.9	12
90	Quantum confinement phenomena in ultrathin GaAs nanowires. , 2016, , .		0

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91	Surface plasmon resonance spectroscopy of single bowtie nano-antennas using a differential reflectivity method. Scientific Reports, 2016, 6, 23203.	3.3	49
92	Optical control of nonlinearly dressed states in an individual quantum dot. Physical Review B, 2016, 93, .	3.2	16
93	Coulomb Mediated Hybridization of Excitons in Coupled Quantum Dots. Physical Review Letters, 2016, 116, 077401.	7.8	25
94	Quantum Effects in Higher-Order Correlators of a Quantum-Dot Spin Qubit. Physical Review Letters, 2016, 117, 027402.	7.8	30
95	Laser intensity effects in carrier-envelope phase-tagged time of flight-photoemission electron microscopy. Applied Physics B: Lasers and Optics, 2016, 122, 1.	2.2	6
96	Monolithically Integrated High-Î² Nanowire Lasers on Silicon. Nano Letters, 2016, 16, 152-156.	9.1	112
97	Stark Effect Spectroscopy of Mono- and Few-Layer MoS₂. Nano Letters, 2016, 16, 1554-1559.	9.1	80
98	Controlled tunneling-induced dephasing of Rabi rotations for high-fidelity hole spin initialization. Physical Review B, 2015, 92, .	3.2	11
99	Linear and non-linear response of lithographically defined plasmonic nanoantennas. , 2015, , .		0
100	Strong transmittance above the light line in mid-infrared two-dimensional photonic crystals. Journal of Applied Physics, 2015, 117, 223101.	2.5	3
101	Virtual Proofs of Reality and their Physical Implementation. , 2015, , .		32
102	A 2D Semiconductorâ€“Selfâ€Assembled Monolayer Photoswitchable Diode. Advanced Materials, 2015, 27, 1426-1431.	21.0	52
103	Tunable Quantum Confinement in Ultrathin, Optically Active Semiconductor Nanowires Via Reverseâ€Reaction Growth. Advanced Materials, 2015, 27, 2195-2202.	21.0	50
104	Alloy Fluctuations Act as Quantum Dot-like Emitters in GaAs-AlGaAs Coreâ€“Shell Nanowires. ACS Nano, 2015, 9, 8335-8343.	14.6	65
105	Towards on-chip generation, routing and detection of non-classical light. , 2015, , .		3
106	On-Chip Generation, Routing, and Detection of Resonance Fluorescence. Nano Letters, 2015, 15, 5208-5213.	9.1	79
107	In situ synthesis of VO₂for tunable mid-infrared photonic devices. RSC Advances, 2015, 5, 59506-59512.	3.6	6
108	Independent dynamic acousto-mechanical and electrostatic control of individual quantum dots in a LiNbO3-GaAs hybrid. Applied Physics Letters, 2015, 106, .	3.3	23

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109	Lattice-Matched InGaAsâ€“InAlAs Coreâ€“Shell Nanowires with Improved Luminescence and Photoresponse Properties. Nano Letters, 2015, 15, 3533-3540.	9.1	46
110	Demonstration of Confined Electron Gas and Steep-Slope Behavior in Delta-Doped GaAs-AlGaAs Coreâ€“Shell Nanowire Transistors. Nano Letters, 2015, 15, 3295-3302.	9.1	60
111	Three-stage decoherence dynamics of an electron spin qubit in an optically active quantum dot. Nature Physics, 2015, 11, 1005-1008.	16.7	96
112	Dynamic acousto-optic control of a strongly coupled photonic molecule. Nature Communications, 2015, 6, 8540.	12.8	50
113	Crystal Phase Quantum Dots in the Ultrathin Core of GaAsâ€“AlGaAs Coreâ€“Shell Nanowires. Nano Letters, 2015, 15, 7544-7551.	9.1	47
114	Photocurrents in a Single InAs Nanowire/Silicon Heterojunction. ACS Nano, 2015, 9, 9849-9858.	14.6	26
115	Ultrafast Photodetection in the Quantum Wells of Single AlGaAs/GaAs-Based Nanowires. Nano Letters, 2015, 15, 6869-6874.	9.1	35
116	Tuning the optical emission of MoS2 nanosheets using proximal photoswitchable azobenzene molecules. Applied Physics Letters, 2014, 105, .	3.3	32
117	Radio frequency occupancy state control of a single nanowire quantum dot. Journal Physics D: Applied Physics, 2014, 47, 394011.	2.8	22
118	Dissipative preparation of the exciton and biexciton in self-assembled quantum dots on picosecond time scales. Physical Review B, 2014, 90, .	3.2	74
119	A carrier relaxation bottleneck probed in single InGaAs quantum dots using integrated superconducting single photon detectors. Applied Physics Letters, 2014, 105, 081107.	3.3	14
120	Valence Band Splitting in Wurtzite InGaAs Nanoneedles Studied by Photoluminescence Excitation Spectroscopy. ACS Nano, 2014, 8, 11440-11446.	14.6	10
121	Highly directed emission from self-assembled quantum dots into guided modes in disordered photonic-crystal waveguides. Physical Review B, 2014, 90, .	3.2	6
122	Emergence of Photoswitchable States in a Grapheneâ€“Azobenzeneâ€“Au Platform. Nano Letters, 2014, 14, 6823-6827.	9.1	40
123	Optical study of lithographically defined, subwavelength plasmonic wires and their coupling to embedded quantum emitters. Nanotechnology, 2014, 25, 075203.	2.6	7
124	Imaging surface plasmon polaritons using proximal self-assembled InGaAs quantum dots. Journal of Applied Physics, 2014, 116, 033101.	2.5	10
125	Optical properties and interparticle coupling of plasmonic bowtie nanoantennas on a semiconducting substrate. Physical Review B, 2014, 90, .	3.2	25
126	Effect of interwire separation on growth kinetics and properties of site-selective GaAs nanowires. Applied Physics Letters, 2014, 105, .	3.3	34

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127	Emitters of N-photon bundles. Nature Photonics, 2014, 8, 550-555.	31.4	136
128	Dynamic Acoustic Control of Individual Optically Active Quantum Dot-like Emission Centers in Heterostructure Nanowires. Nano Letters, 2014, 14, 2256-2264.	9.1	64
129	Laterally self-ordered silicon-germanium islands with optimized confinement properties. Applied Physics Letters, 2013, 103, 063105.	3.3	3
130	Lasing from individual GaAs-AlGaAs core-shell nanowires up to room temperature. Nature Communications, 2013, 4, 2931.	12.8	207
131	Enhanced Luminescence Properties of InAsâ€“InAsP Coreâ€“Shell Nanowires. Nano Letters, 2013, 13, 6070-6077.	9.1	73
132	All optical quantum control of a spin-quantum state and ultrafast transduction into an electric current. Scientific Reports, 2013, 3, 1906.	3.3	25
133	High Mobility One- and Two-Dimensional Electron Systems in Nanowire-Based Quantum Heterostructures. Nano Letters, 2013, 13, 6189-6196.	9.1	56
134	Spontaneous Alloy Composition Ordering in GaAs-AlGaAs Coreâ€“Shell Nanowires. Nano Letters, 2013, 13, 1522-1527.	9.1	116
135	Optimisation of NbN thin films on GaAs substrates for in-situ single photon detection in structured photonic devices. Journal of Applied Physics, 2013, 113, 143507.	2.5	19
136	Role of microstructure on optical properties in high-uniformity In<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mrow /><mml:mrow><mml:mn>1</mml:mn><mml:mo>âˆ’</mml:mo><mml:mi>x</mml:mi></mml:mrow></mml:msub></mml:math>Ga<mml: xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mrow /><mml:mi>x</mml:mi></mml:msub></mml:math>As nanowire arrays: Evidence of a wider wurtzite band gap. Physical Review B, 2013, 87, .	3.2	46
137	Acoustically regulated carrier injection into a single optically active quantum dot. Physical Review B, 2013, 88, .	3.2	41
138	Probing ultrafast carrier tunneling dynamics in individual quantum dots and molecules. Annalen Der Physik, 2013, 525, 49-58.	2.4	15
139	On-chip time resolved detection of quantum dot emission using integrated superconducting single photon detectors. Scientific Reports, 2013, 3, 1901.	3.3	93
140	Probing the trapping and thermal activation dynamics of excitons at single twin defects in GaAsâ€“AlGaAs coreâ€“shell nanowires. New Journal of Physics, 2013, 15, 113032.	2.9	30
141	Surface acoustic wave-driven carrier dynamics as a contact-less probe for mobilities of photogenerated carriers in undoped nanowires. , 2013, , .		0
142	A three-dimensional silicon photonic crystal nanocavity with enhanced emission from embedded germanium islands. New Journal of Physics, 2012, 14, 083035.	2.9	11
143	Climbing the Jaynesâ€“Cummings ladder by photon counting. Journal of Nanophotonics, 2012, 6, 061803.	1.0	42
144	Rate-limiting mechanisms in high-temperature growth of catalyst-free InAs nanowires with large thermal stability. Nanotechnology, 2012, 23, 235602.	2.6	37

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145	Universal signatures of lasing in the strong coupling regime. Proceedings of SPIE, 2012, , .	0.8	5
146	A Waveguide-Coupled On-Chip Single-Photon Source. Physical Review X, 2012, 2, .	8.9	115
147	Broadband Purcell enhanced emission dynamics of quantum dots in linear photonic crystal waveguides. Journal of Applied Physics, 2012, 112, .	2.5	19
148	Probing ultrafast charge and spin dynamics in a quantum dot molecule. , 2012, , .		0
149	All optical preparation, storage, and readout of a single spin in an individual quantum dot. Proceedings of SPIE, 2012, , .	0.8	2
150	High compositional homogeneity in In-rich InGaAs nanowire arrays on nanoimprinted SiO₂/Si (111). Applied Physics Letters, 2012, 101, 043116.	3.3	54
151	Surface acoustic wave controlled charge dynamics in a thin InGaAs quantum well. JETP Letters, 2012, 95, 575-580.	1.4	16
152	Diameter dependent optical emission properties of InAs nanowires grown on Si. Applied Physics Letters, 2012, 101, 053103.	3.3	36
153	Coupling of guided surface plasmon polaritons to proximal self-assembled InGaAs Quantum Dots. Proceedings of SPIE, 2012, , .	0.8	2
154	Quantum dynamics of damped and driven anharmonic oscillators. Physica Status Solidi C: Current Topics in Solid State Physics, 2012, 9, 1296-1302.	0.8	1
155	Electrical Control of Interdot Electron Tunneling in a Double InGaAs Quantum-Dot Nanostructure. Physical Review Letters, 2012, 108, 197402.	7.8	78
156	High-fidelity optical preparation and coherent Larmor precession of a single hole in an (In,Ga)As quantum dot molecule. Physical Review B, 2012, 85, .	3.2	36
157	Highly nonlinear excitonic Zeeman spin splitting in composition-engineered artificial atoms. Physical Review B, 2012, 85, .	3.2	24
158	Luminescence spectra of quantum dots in microcavities. III. Multiple quantum dots. Physical Review B, 2011, 84, .	3.2	32
159	Directional and Dynamic Modulation of the Optical Emission of an Individual GaAs Nanowire Using Surface Acoustic Waves. Nano Letters, 2011, 11, 1512-1517.	9.1	56
160	Direct measurement of plasmon propagation lengths on lithographically defined metallic waveguides on GaAs. Journal of Applied Physics, 2011, 110, 123106.	2.5	7
161	Absence of vapor-liquid-solid growth during molecular beam epitaxy of self-induced InAs nanowires on Si. Applied Physics Letters, 2011, 98, 123114.	3.3	69
162	Direct Observation of a Noncatalytic Growth Regime for GaAs Nanowires. Nano Letters, 2011, 11, 3848-3854.	9.1	119

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163	Direct observation of metastable hot trions in an individual quantum dot. Physical Review B, 2011, 84, .	3.2	23
164	Strong Photoluminescence Enhancement from Colloidal Quantum Dot Near Silver Nano-Island Films. Journal of Fluorescence, 2011, 21, 539-543.	2.5	4
165	Electrical control of the excitonâ€“biexciton splitting in self-assembled InGaAs quantum dots. Nanotechnology, 2011, 22, 325202.	2.6	23
166	Excited state quantum couplings and optical switching of an artificial molecule. Physical Review B, 2011, 84, .	3.2	17
167	Fabrication of high-Q silicon-based three-dimensional photonic crystal nanocavity and its lasing oscillation with InAs quantum-dot gain. , 2011, , .		1
168	Correlation between emission intensity of self-assembled germanium islands and quality factor of silicon photonic crystal nanocavities. Physical Review B, 2011, 84, .	3.2	12
169	Observation and explanation of strong electrically tunable exciton<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:mi>g</mml:mi></mml:mrow></mml:math>factors in composition engineered In(Ga)As quantum dots. Physical Review B, 2011, 83, .	3.2	34
170	Nonresonant feeding of photonic crystal nanocavity modes by quantum dots. Journal of Applied Physics, 2011, 109, 102404.	2.5	12
171	Shape control of quantum dots studied by cross-sectional scanning tunneling microscopy. Journal of Applied Physics, 2011, 109, 102413.	2.5	13
172	Coplanar stripline antenna design for optically detected magnetic resonance on semiconductor quantum dots. Review of Scientific Instruments, 2011, 82, 074707.	1.3	8
173	Ultrafast few-fermion dynamics in single self-assembled InGaAs/GaAs quantum dots. , 2011, , .		0
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